# **Monolithic Amplifier**

TSS-23HLN+

 $50\Omega$  30MHz to 2 GHz



#### CASE STYLE: DQ1225

## **The Big Deal**

- Ultra-High IP3, +42.6 dBm typ.
- Medium power, +28.5 dBm typ.
- Excellent Noise Figure, 1.4 dB typ.
- Shutdown feature

## **Product Overview**

TSS-23HLN+ (RoHS compliant) is an advanced wideband amplifier with shutdown feature. It is fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the TSS-23HLN+ has good input and output return loss over a broad frequency range. TSS-23HLN+ is enclosed in a 3mm x 3mm, 12-lead MCLP package and has very good thermal performance.

## **Key Features**

| Feature  | Advantages   |
|--|--|
| Broad Band: 30MHz to 2GHz  | Broadband covering primary wireless communications bands: VHF, UHF, Cellular   |
| Extremely High IP3<br>39.6 dBm typical at 30 MHz<br>42.6 dBm typical at 1GHz | The TSS-23HLN+ matches industry leading IP3 performance relative to device size and power consumption. The combination of the design and E-PHEMT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being approximately 13-15 dB above the P1dB point. This feature makes this amplifier ideal for use in:  • Driver amplifiers for complex waveform up converter paths  • Drivers in linearized transmit systems  • Secondary amplifiers in ultra-High Dynamic range receivers |
| Shutdown feature   | Allow users to turn on and off the amplifier with pulsed signals while keeping the power supply at constant voltage to minimize DC power consumption   |
| Low Noise Figure<br>1.4 dB at 1 GHz  | Enables lower system noise figure performance and along with High OIP3 provides high dynamic range   |
| High P1dB , 28.5 dBm at 1<br>GHz   | High P1dB, High OIP3, Low NF results in a very dynamic range preventing amplifier saturation under strong interfering signals.   |

#### **Product Features**

- High IP3, 42.6 dBm typ. at 1GHz
- Gain, 21.8 dB typ. at 1 GHz
- Low noise figure, 1.4 dB at 1 GHz
- High P1dB, 28.5 dBm at 1 GHz
- Shutdown feature

### **Typical Applications**

- Base station infrastructure
- CATV
- Cellular

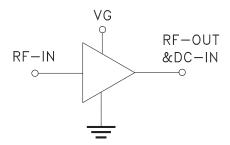


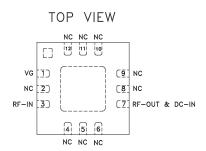
+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

### **General Description**

TSS-23HLN+ (RoHS compliant) is an advanced wideband amplifier with shutdown feature. It is fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the TSS-23HLN+ has good input and output return loss over a broad frequency range. TSS-23HLN+ is enclosed in a 3mm x 3mm, 12-lead MCLP package and has very good thermal performance.

#### simplified schematic and pad description





| Function         | Pin Number   | Description                        |
|------------------|--------------|------------------------------------|
| RF IN            | 3            | RF Input                           |
| RF-OUT and DC-IN | 7            | RF Output and DC Bias              |
| GND              | Paddle       | Connections to ground.             |
| NC               | 2, 4-6, 8-12 | No connection, grounded externally |
| VG               | 1            | Control voltage for shutdown (VG)  |

## Electrical Specifications $^1$ at 25 $^{\circ}$ C & 50 $\Omega$ , unless otherwise noted.

| Parameter  | Condition<br>(MHz) |           | Amplifier-ON<br>VDD = 8V |      | Amplifier-OFF<br>VDD = 8V | Units   |  |
|--|--------------------|-----------|--------------------------|------|---------------------------|---------|--|
|  |                    | Min. Typ. |                          | Max. | Тур.                      |         |  |
| Frequency Range  |                    | 30        |                          | 2000 | 30-2000                   | MHz     |  |
|  | 30                 |           | 1.4                      |      | _                         | dB      |  |
|  | 500                |           | 1.4                      |      | _                         |         |  |
| Noise Figure   | 1000               |           | 1.4                      |      | _                         |         |  |
|  | 1500               |           | 1.5                      |      | _                         |         |  |
|  | 2000               |           | 1.6                      |      | _                         |         |  |
|  | 30                 | 20.9      | 23.3                     | 25.5 | -21                       | dB      |  |
|  | 500                | _         | 22.4                     | _    | -21                       |         |  |
| Gain   | 1000               | 19.5      | 21.8                     | 23.8 | -23                       |         |  |
|  | 1500               | _         | 21.1                     | _    | -25                       |         |  |
|  | 2000               | 18.1      | 20.3                     | 22.1 | -28                       |         |  |
| Reversed Isolation                                     | 30-2000            |           | 27                       |      | 26                        | dB      |  |
|  | 30                 |           | 11                       |      | 12                        | dB      |  |
|  | 500                |           | 12                       |      | 12                        |         |  |
| Input Return Loss                                      | 1000               |           | 10                       |      | 12                        |         |  |
|  | 1500               |           | 11                       |      | 15                        |         |  |
|  | 2000               |           | 12                       |      | 20                        |         |  |
|  | 30                 |           | 15                       |      | 2                         | dB      |  |
|  | 500                |           | 14                       |      | 2                         |         |  |
| Output Return Loss                                     | 1000               |           | 12                       |      | 2                         |         |  |
|  | 1500               |           | 10                       |      | 2                         |         |  |
|  | 2000               |           | 8                        |      | 2                         |         |  |
|  | 30                 |           | 26.2                     |      |                           | dBm     |  |
|  | 500                |           | 27.9                     |      |                           |         |  |
| Output Power @1dB compression AMP-ON                   | 1000               |           | 28.5                     |      |                           |         |  |
|  | 1500               |           | 28.1                     |      |                           |         |  |
|  | 2000               |           | 27.7                     |      |                           |         |  |
|  | 30                 | _         | 39.6                     |      |                           | dBm     |  |
|  | 500                | _         | 41.6                     |      |                           |         |  |
| Output IP3 (Pout = 0dBm/Tone)                          | 1000               | _         | 42.6                     |      |                           |         |  |
|  | 1500               | 38.2      | 42.6                     |      |                           |         |  |
|  | 2000               | _         | 41.8                     |      |                           |         |  |
| Device Operating Voltage (VDD)                         |                    | 7.6       | 8                        | 8.4  | 8                         | V       |  |
| Device Operating Current (ID)                          |                    |           | 236                      | 249  | 8                         | mA      |  |
| Control Voltage (VG)                                   |                    |           | 0                        |      | 5                         | V       |  |
| DC Current (ID) Variation Vs. Temperature <sup>2</sup> |                    |           | -225                     |      |                           | uA/degC |  |
| DC Current (ID) Variation Vs. Voltage                  |                    |           | 0.0263                   |      |                           | mA/mV   |  |
| Thermal Resistance                                     |                    |           | 23.3                     |      |                           | degC/W  |  |

<sup>1.</sup> Measured on Mini-Circuits Characterization test board TB-TSS-23HLN+. See Characterization Test Circuit (Fig. 1) 2. (Current at 95°C — Current at -45°C)/140

## **Absolute Maximum Ratings<sup>3</sup>**

| Parameter                                       | Ratings  |  |  |
|---|--|--|--|
| Operating Temperature (ground lead)             | -40°C to 95°C  |  |  |
| Storage Temperature                             | -65°C to 150°C   |  |  |
| Total Power Dissipation                         | 3.3W   |  |  |
| Input Power                                     | 28 dBm (5 minutes max.)<br>15 dBm (continuos) for 0.03-1 GHz<br>18 dBm (continuos) for 1-2 GHz |  |  |
| DC Voltage V <sub>DD</sub> <sup>4</sup> (Pad 7) | 10V  |  |  |
| DC Voltage V <sub>G</sub> <sup>5</sup> (Pad 1)  | 10V  |  |  |

 <sup>&</sup>lt;sup>3</sup> Permanent damage may occur if these limits are exceeded.
 <sup>4</sup> Measured by keeping V<sub>0</sub>=0V.
 <sup>5</sup> Measured by keeping V<sub>0</sub>0=8V.

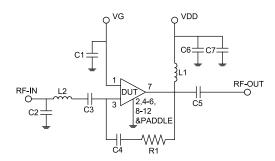
## Control Voltage (V<sub>G</sub>) Fig. 1

|               | Min. | Тур. | Max. | Units |
|---------------|------|------|------|-------|
| Amplifier-ON  | _    | 0    | 0.7  | V     |
| Amplifier-OFF | 1.9  | 5    | _    | V     |

#### **Switching Specifications**

| Parameter                |                                  |  | Тур.  | Max. | Units |
|--------------------------|----------------------------------|--|-------|------|-------|
| Amplifiar ON to Chutdour | OFF TIME (50% Control to 10% RF) |  | 5.3   |      |       |
| Amplifier ON to Shutdown | FALL TIME (90 to 10% RF)         |  | 7.3   |      | μS    |
| A life Object ON         | ON TIME (50% Control to 90% RF)  |  | 77.7  |      | _     |
| Amplifier Shutdown to ON | RISE TIME (10% to 90% RF)        |  | 54.2  |      | μS    |
| Control Voltage Leakage  |                                  |  | 633.3 | _    | mV    |

### **Characterization Test Circuit / Recommended Application Circuit**



| Component | Size | Value   | Part Number        | Manufacturer |
|-----------|------|---------|--------------------|--------------|
| C1        | 0402 | 0.1uF   | GRM155R71C104KA88D | Murata       |
| C2        | 0402 | 1.2pF   | GRM1555C1H1R2CA1D  | Murata       |
| C3        | 0402 | 0.1uF   | GRM155R71C104KA88D | Murata       |
| C4        | 0402 | 0.1uF   | GRM155R71C104KA88D | Murata       |
| C5        | 0402 | 1000pF  | GRM1555C1H102JA01D | Murata       |
| C6        | 0402 | 10000pF | GRM155R71E103KA01D | Murata       |
| C7        | 0402 | 0.1uF   | GRM155R71C104KA88D | Murata       |
| L1        | 0805 | 680nH   | 0805LS-681XJLB     | Coilcraft    |
| L2        | 0402 | 1.0nH   | 0402CS-1N0XJLW     | Coilcraft    |
| R1        | 0402 | 1.2K0hm | RK73H1ETTP1201F    | Koa          |

Fig 1. Block diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-TSS-13LN+) Gain, Return loss, Output power at 1dB compression (P1dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

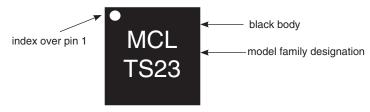
#### Conditions:

- 1. Gain and Return Loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, +0dBm/tone at output.
- 3. Switching Time

RF Signal: Pin=-25 dBm, f<sub>RF</sub>=500 MHz.

 $V_{DD}$ =8V DC,  $V_{G}$ =Pulse signal at 1 KHz with  $V_{HIGH}$ =5V,  $V_{LOW}$ =0V, 50% duty cycle.

## **Product Marking**



Marking may contain other features or characters for internal lot control

| Additional Detailed Technical Information additional information is available on our dash board. To access this information click here |   |  |  |  |
|--|---|--|--|--|
|  | Data Table  |  |  |  |
| Performance Data   | Swept Graphs  |  |  |  |
|  | S-Parameter (S2P Files) Data Set (.zip file)                  |  |  |  |
| Case Style   | DQ1225 Plastic package, exposed paddle lead finish: Matte-Tin |  |  |  |
| Tape & Reel  | F66   |  |  |  |
| Standard quantities available on reel  | 7" reels with 20, 50, 100, 200, 500 or 1K devices             |  |  |  |
| Suggested Layout for PCB Design  | PL-619  |  |  |  |
| Evaluation Board   | TB-TSS-23HLN+   |  |  |  |
| Environmental Ratings  | ENV08T9   |  |  |  |

#### **ESD Rating**

Human Body Model (HBM): Class 1A (Pass 250 V) in accordance with ANSI/ESD STM 5.1 - 2001

#### **MSL Test Flow Chart** Start Visual Electrical Test SAM Analysis Inspection Soak Reflow 3 cycles, Bake at 125°C, 85°C/85RH 260°C 24 hours 168 hours SAM Analysis **Flectrical Test** Stop Inspection

#### **Additional Notes**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
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